# **1.8V / 2.5V Differential 4:1 Mux w/Input Equalizer to 1:2 CML Clock/Data Fanout / Translator**

# Multi-Level Inputs w/ Internal Termination

#### Description

The NB6VQ572M is a high performance differential 4:1 Clock / Data input multiplexer and a 1:2 CML Clock / Data fanout buffer that operates up to 5 GHz / 6.5 Gbps respectively with a 1.8 V or 2.5 V power supply.

Each INx /  $\overline{INx}$  input pair incorporates a fixed Equalizer Receiver, which when placed in series with a Clock / Data path, will enhance the degraded signal transmitted across an FR4 backplane or cable interconnect. For applications that do not require Equalization, consider the NB7V572M, which is pin-compatible to the NB6VQ572M.

The differential Clock / Data inputs have internal 50  $\Omega$  termination resistors and will accept differential LVPECL, CML, or LVDS logic levels. The NB6VQ572M incorporates a pair of Select pins that will choose one of four differential inputs and will produce two identical CML output copies of Clock or Data.

As such, the NB6VQ572M is ideal for SONET, GigE, Fiber Channel, Backplane and other Clock/Data distribution applications. The two differential CML outputs will swing 400 mV when externally loaded and terminated with a 50  $\Omega$  resistor to  $V_{CC}$  and are optimized for low skew and minimal jitter.

The NB6VQ572M is offered in a low profile 5x5 mm 32-pin QFN Pb-Free package. Application notes, models, and support documentation are available at <u>www.onsemi.com</u>. The NB6VQ572M is a member of the ECLinPS MAX<sup>TM</sup> family of high performance clock products.

#### Features

- Input Data Rate > 6.5 Gb/s Typical
- Data Dependent Jitter < 10 ps
- Maximum Input Clock Frequency > 5 GHz Typical
- Random Clock Jitter < 0.8 ps RMS
- Low Skew 1:2 CML Outputs, < 15 ps max
- 4:1 Multi-Level Mux Inputs, accepts LVPECL, CML, LVDS
- 175 ps Typical Propagation Delay
- 45 ps Typical Rise and Fall Times



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### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 10 of this data sheet.

- Differential CML Outputs, 400 mV Peak-to-Peak, Typical
- Operating Range:  $V_{CC}$  = 1.71 V to 2.625 V with GND = 0 V
- Internal 50  $\Omega$  Input Termination Resistors
- VREFAC Reference Output
- QFN-32 Package, 5mm x 5mm, Pb-Free
- -40°C to +85°C Ambient Operating Temperature
- These are Pb-Free Devices







Figure 2. Pinout: QFN-32 (Top View)

## Table 1. INPUT SELECT FUNCTION TABLE

SEL1*	SEL0*	Clock / Data Input Selected
0	0	IN0 Input Selected
0	1	IN1 Input Selected
1	0	IN2 Input Selected
1	1	IN3 Input Selected

\*Defaults HIGH when left open.

## Table 2. PIN DESCRIPTION

Pin Number	Pin Name	I/O	Pin Description
1, 4 5, 8 25, 28 29, 32	IN0, <u>IN0</u> IN1, <u>IN1</u> IN2, <u>IN2</u> IN3, IN3	LVPECL, CML, LVDS Input	Noninverted, Inverted, Differential Clock or Data Inputs
2, 6 26, 30	VT0, VT1 VT2, VT3		Internal 100 $\Omega$ Center-tapped Termination Pin for INx / $\overline{\text{INx}}$
15 18	SEL0 SEL1	LVTTL/LVCMOS Input	Input Select pins, default HIGH when left open through a 94 k $\Omega$ pullup resistor. Input logic threshold is V <sub>CC</sub> /2. See Select Function, Table 1.
14, 19	NC	-	No Connect
10, 13, 16 17, 20, 23	V <sub>CC</sub>	-	Positive Supply Voltage.
11, 12 21, 22	<u>Q0</u> , Q0 <u>Q1</u> , Q1	CML Output	Inverted, Non-inverted Differential Outputs.
9, 24	GND		Negative Supply Voltage
3 7 27 31	VREFAC0 VREFAC1 VREFAC2 VREFAC3	-	Output Voltage Reference for Capacitor-Coupled Inputs
_	EP	_	The Exposed Pad (EP) on the QFN-32 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be at- tached to a heat-sinking conduit. The pad is electrically connected to the die, and must be electrically connected to GND.

In the differential configuration when the input termination pins (VT0, VT1, VT2, VT3) are connected to a common termination voltage or left open, and if no signal is applied on INx/INx input, then the device will be susceptible to self-oscillation.
 All V<sub>CC</sub>, and GND pins must be externally connected to a power supply for proper operation.

### **Table 3. ATTRIBUTES**

Characteristic	S	Value
ESD Protection	Human Body Model Machine Model	> 2 kV > 200 V
R <sub>PU</sub> – SELx Input Pullup Resistor		94kΩ
Moisture Sensitivity (Note 3)	QFN-32	Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count		221
Meets or exceeds JEDEC Spec EIA/JE	SD78 IC Latchup Test	

3. For additional information, see Application Note AND8003/D.

#### **Table 4. MAXIMUM RATINGS**

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	Positive Power Supply	GND = 0 V		3.0	V
V <sub>IN</sub>	Positive Input Voltage	GND = 0 V		–0.5 to V <sub>CC</sub> +0.5	V
V <sub>INPP</sub>	Differential Input Voltage  IN - IN			1.89	V
l <sub>out</sub>	Output Current Through $R_T$ (50 $\Omega$ Resistor)			± 40	mA
I <sub>IN</sub>	Input current Through RT (50 $\Omega$ Resistor)			± 40	mA
IVREFAC	V <sub>REFAC</sub> Sink or Source Current			±1.5	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient) (Note 4)	0 lfpm 500 lfpm	QFN-32 QFN-32	31 27	°C/W °C/W
$\theta_{\text{JC}}$	Thermal Resistance (Junction-to-Case) (Note 4)		QFN-32	12	°C/W
T <sub>sol</sub>	Wave Solder	≤ 20 sec		265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

Symbol	Characteristic		Min	Тур	Max	Unit
POWER SUPPLY						
V <sub>CC</sub>	Power Supply Voltage V <sub>CC</sub> = V <sub>CC</sub> =	2.5 V 1.8 V	2.375 1.71	2.5 1.8	2.625 1.89	V
Icc	$ \begin{array}{llllllllllllllllllllllllllllllllllll$		70 60	105 85	140 120	mA

#### CML OUTPUTS (Note 6)

V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = 2.5 V V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> - 30 2470 1770	V <sub>CC</sub> – 10 2490 1790	V <sub>CC</sub> 2500 1800	mV
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = 2.5 V V <sub>CC</sub> =1.8 V	V <sub>CC</sub> – 550 1950 1250	V <sub>CC</sub> – 450 2050 1350	V <sub>CC</sub> – 350 2150 1450	mV

#### DIFFERENTIAL CLOCK INPUTS DRIVEN SINGLE-ENDED (Figures 7 and 8) (Note 7)

V <sub>IH</sub>	Single-ended Input HIGH Voltage	V <sub>th</sub> + 100	V <sub>CC</sub>	mV
VIL	Single-ended Input LOW Voltage	GND	V <sub>th</sub> – 100	mV
V <sub>th</sub>	Input Threshold Reference Voltage Range (Note 8)	1100	V <sub>CC</sub> – 100	mV
V <sub>ISE</sub>	Single-ended Input Voltage (VIH - VIL)	200	1200	mV

#### VREFAC

V <sub>REFAC</sub>	Output Reference Voltage (100 µA Load)	V <sub>CC</sub> – 700	V <sub>CC</sub> – 550	V <sub>CC</sub> – 450	mV	
DIFFEREN	DIFFERENTIAL INPUTS DRIVEN DIFFERENTIALLY (Figures 9 and 10) (Note 9)					

V <sub>IHD</sub>	Differential Input HIGH Voltage (IN, IN)	1200	V <sub>CC</sub>	mV
V <sub>ILD</sub>	Differential Input LOW Voltage (IN, IN)	0	V <sub>IHD</sub> – 100	mV
$V_{\text{ID}}$	Differential Input Voltage (IN, ĪN) (V <sub>IHD</sub> - V <sub>ILD</sub> )	100	1200	mV
V <sub>CMR</sub>	Input Common Mode Range (Differential Configuration, Note 10) (Figure 11)	1150	V <sub>CC</sub> – 50	mV
I <sub>IH</sub>	Input HIGH Current IN / IN (VTIN/VTIN Open)	-150	150	μΑ
IIL	Input LOW Current IN / IN (VTIN/VTIN Open)	-150	150	μΑ

**CONTROL INPUT** (SELx Pin) Input HIGH Voltage for Control Pin  $V_{CC}$ V VIH V<sub>CC</sub> x 0.65 VIL GND V Input LOW Voltage for Control Pin  $V_{CC} \ge 0.35$ Input HIGH Current -150 150  $I_{\rm H}$ μΑ -150 150  $I_{|L|}$ Input LOW Current μΑ

#### **TERMINATION RESISTORS**

R <sub>TIN</sub>	Internal Input Termination Resistor (Measured from INx to VTx)	45	50	55	Ω
R <sub>TOUT</sub>	Internal Output Termination Resistor	45	50	55	Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

5. Input and Output parameters vary 1:1 with V<sub>CC</sub>. 6. CML outputs loaded with 50  $\Omega$  to V<sub>CC</sub> for proper operation.

7.  $V_{th}$ ,  $V_{IH}$ ,  $V_{IL}$ , and  $V_{ISE}$  parameters must be complied with simultaneously.

8. V<sub>th</sub> is applied to the complementary input when operating in single-ended mode.

9.  $V_{IHD}$ ,  $V_{ILD}$ ,  $V_{ID}$  and  $V_{CMR}$  parameters must be complied with simultaneously. 10.  $V_{CMR}$  min varies 1:1 with GND,  $V_{CMR}$  max varies 1:1 with  $V_{CC}$ . The  $V_{CMR}$  range is referenced to the most positive side of the differential input signal.

Symbol	Characteristic	Min	Тур	Мах	Unit
f <sub>MAX</sub>	Maximum Input Clock Frequency $V_{OUT} \ge 250 \text{ mV}$	5	6		GHz
f <sub>DATAMAX</sub>	Maximum Operating Data Rate NRZ, (PRBS23)	6.5	8		Gbps
f <sub>SEL</sub>	Maximum Toggle Frequency, SELx	4	10		MHz
V <sub>OUTPP</sub>	Output Voltage Amplitude (@ V <sub>INPPmin</sub> ) (Note 12) (Figure 12) $f_{in} \leq 5 \mbox{ GHz}$	250	400		mV
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay to Differential@ 1 GHz INx/INx to Qx/QxOutputs Measured at Differential@ 50 MHz SELx to QxCrosspoint	100	175 7	250 20	ps ns
t <sub>PD Tempco</sub>	Differential Propagation Delay Temperature Coefficient		50		∆fs/°C
t <sub>skew</sub>	Output – Output skew (within device) (Note 13) Device – Device skew (t <sub>pdmax</sub> – t <sub>pdmin</sub> )		0 30	15 100	ps
t <sub>DC</sub>	Output Clock Duty Cycle (Reference Duty Cycle = 50%) $$f_{\rm IN} \le 5~{\rm GHz}$$	45	50	55	%
Φ <sub>N</sub>	Phase Noise, f <sub>in</sub> = 1 GHz 10 kHz 100 kHz 1 MHz 10 MHz 20 MHz 40 MHz		-135 -136 -149 -150 -150 -151		dBc
$t_{\int \Phi N}$	Integrated Phase Jitter (Figure TBD) f <sub>in</sub> = 1 GHz, 12 kHz – 20 MHz Offset (RMS)		35		fs
<b>UITTER</b>	$ \begin{array}{ll} \mbox{Random Clock Jitter, RJ (Note 14)} & f_{in} \leq 5 \mbox{ GHz} \\ \mbox{Deterministic Jitter, DJ (Note 15)} & f_{in} \leq 6.5 \mbox{ Gbps (12" FR4)} \end{array} $		0.2	0.8 10	ps RMS ps pk–pk
	Crosstalk Induced Jitter (Adjacent Channel) (Note 17)			0.7	ps RMS
VINPP	Input Voltage Swing (Differential Configuration) (Note 16)	100		1200	mV
t <sub>r,</sub> , t <sub>f</sub>	Output Rise/Falltimes @ 1 GHz; (20% – 80%), $V_{IN}$ = 400 mV Qx, $\overline{Qx}$	25	45	65	ps

Table 6. AC CHARACTERISTICS	$V_{CC}$ = 1.71 V to 2.625 V, GND = 0 V, $T_A$ = -40°C to +85°C (No	ote 11)
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NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

11. Measured using a 100 mVpk-pk source, 50% duty cycle clock source. All output loading with external 50  $\Omega$  to V<sub>CC</sub>. Input edge rates 40 ps (20% - 80%).

12. Output voltage swing is a single-ended measurement operating in differential mode.

13. Skew is measured between outputs under identical transitions and conditions. Duty cycle skew is defined only for differential operation when the delays are measured from crosspoint of the inputs to the crosspoint of the outputs.

14. Additive RMS jitter with 50% duty cycle clock signal.

15. Additive Peak-to-Peak data dependent jitter with input NRZ data at PRBS23.

16. Input voltage swing is a single-ended measurement operating in differential mode.

17. Crosstalk is measured at the output while applying two similar clock frequencies that are asynchronous with respect to each other at the inputs.



Figure 3. Clock Output Voltage Amplitude (V<sub>OUTPP</sub>) vs. Input Frequency (f<sub>in</sub>) at Ambient Temperature (Typical)





Figure 4. Inside Eye Height vs. Input Data Rate (Gbps) at Ambient Temperature (typical), FR4 = 12"



Figure 5. Typical NB6VQ572M Equalizer Application and Interconnect with PRBS23 Pattern at 6.5 Gbps









Figure 8. V<sub>th</sub> Diagram

















Figure 13. SELx to Qx Timing Diagram





Figure 15. LVDS Interface



Figure 16. Standard 50  $\Omega$  Load CML Interface



Figure 17. Capacitor–Coupled Differential Interface (V<sub>T</sub> Connected to V<sub>REFAC</sub>)

\*V<sub>REFAC</sub> bypassed to ground with a 0.01  $\mu$ F capacitor.



Figure 18. Typical CML Output Structure and Termination

#### **DEVICE ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NB6VQ572MMNG	QFN-32 (Pb-free)	74 Units / Rail
NB6VQ572MMNR4G	QFN-32 (Pb-free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS



NOTES:

- 1. DIMENSIONS AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED 2 з.
- TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM TERMINAL COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.800	0.900	1.000	
A1	0.000	0.025	0.050	
A3	0.200 REF			
b	0.180	0.250	0.300	
D	5.00 BSC			
D2	2.950	3.100	3.250	
Е	5.00 BSC			
E2	2.950	3.100	3.250	
е	0.500 BSC			
ĸ	0.200			
L	0.300	0.400	0.500	

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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